

# SN54LVTZ245, SN74LVTZ245 3.3-V ABT OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS303C – DECEMBER 1993 – REVISED JANUARY 1996

- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low-Static Power Dissipation
- High-Impedance State During Power Up and Power Down
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V  $V_{CC}$ )
- Support Unregulated Battery Operation Down to 2.7 V
- Typical  $V_{OLP}$  (Output Ground Bounce) < 0.8 V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Bus-Hold Data Inputs Eliminate the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Ceramic (J) DIPs

## description

These octal bus transceivers are designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

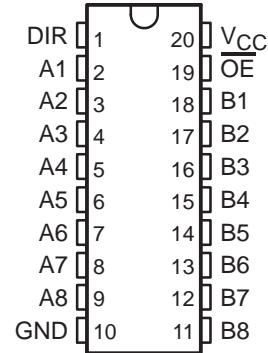
These devices are designed for asynchronous communication between data buses. They transmit data from the A bus to the B bus or from the B bus to the A bus, depending upon the logic level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the devices so the buses are effectively isolated.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

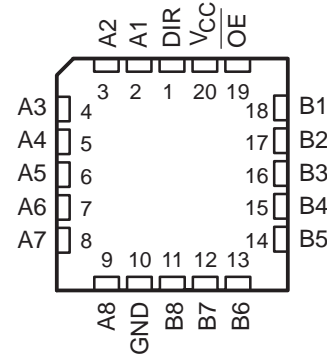
The SN74LVTZ245 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54LVTZ245 is characterized for operation over the full military temperature range of  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ . The SN74LVTZ245 is characterized for operation from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .

SN54LVTZ245 . . . J PACKAGE  
SN74LVTZ245 . . . DB, DW, OR PW PACKAGE  
(TOP VIEW)



SN54LVTZ245 . . . FK PACKAGE  
(TOP VIEW)



FUNCTION TABLE

INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

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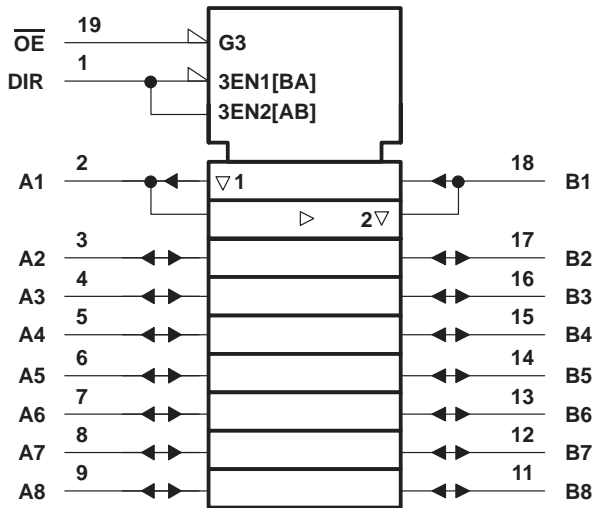
# SN54LVTZ245, SN74LVTZ245

## 3.3-V ABT OCTAL BUS TRANSCEIVERS

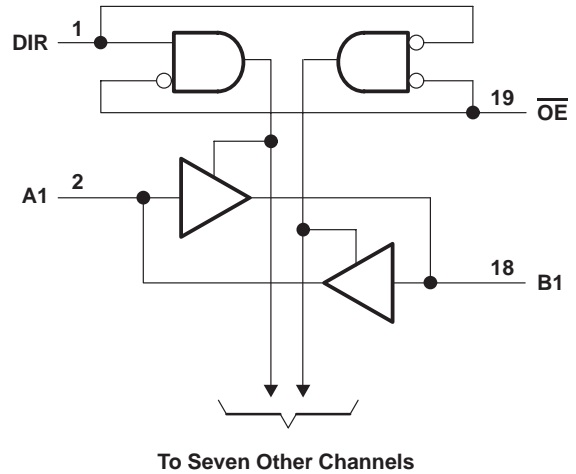
### WITH 3-STATE OUTPUTS

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#### logic symbol†



#### logic diagram (positive logic)



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.  
Pin numbers shown are for the DB, DW, PW, and J packages.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, $V_{CC}$ .....	-0.5 V to 4.6 V
Input voltage range, $V_I$ (see Note 1) .....	-0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, $V_O$ (see Note 1) ....	-0.5 V to 7 V
Current into any output in the low state, $I_{OL}$ : SN54LVTZ245 .....	96 mA
SN74LVTZ245 .....	128 mA
Current into any output in the high state, $I_{OH}$ (see Note 2): SN54LVTZ245 .....	48 mA
SN74LVTZ245 .....	64 mA
Input clamp current, $I_{IK}$ ( $V_I < 0$ ) .....	-50 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ ) .....	-50 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air) (see Note 3): DB package .....	0.6 W
DW package .....	1.6 W
PW package .....	0.7 W
Storage temperature range, $T_{stg}$ .....	-65°C to 150°C

‡ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.  
2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .  
3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

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**recommended operating conditions (see Note 4)**

		SN54LVTZ245		SN74LVTZ245		UNIT
		MIN	MAX	MIN	MAX	
$V_{CC}$	Supply voltage	2.7	3.6	2.7	3.6	V
$V_{IH}$	High-level input voltage	2		2		V
$V_{IL}$	Low-level input voltage		0.8		0.8	V
$V_I$	Input voltage		5.5		5.5	V
$I_{OH}$	High-level output current		-24		-32	mA
$I_{OL}$	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled			10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	200		200		$\mu$ s/V
$T_A$	Operating free-air temperature	-55	125	-40	85	$^{\circ}$ C

NOTE 4: Unused control inputs must be held high or low to prevent them from floating.

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## 3.3-V ABT OCTAL BUS TRANSCEIVERS

### WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN54LVTZ245		SN74LVTZ245		UNIT
			MIN	TYP†	MAX	MIN	
$V_{IK}$	$V_{CC} = 2.7\text{ V}$ , $I_I = -18\text{ mA}$		-1.2		-1.2		V
$V_{OH}$	$V_{CC} = \text{MIN to MAX}^\ddagger$ , $I_{OH} = -100\ \mu\text{A}$		$V_{CC} - 0.2$		$V_{CC} - 0.2$		V
	$V_{CC} = 2.7\text{ V}$ , $I_{OH} = -8\text{ mA}$		2.4		2.4		
	$V_{CC} = 3\text{ V}$	$I_{OH} = -24\text{ mA}$	2		2		
$I_{OH} = -32\text{ mA}$							
$V_{OL}$	$V_{CC} = 2.7\text{ V}$	$I_{OL} = 100\ \mu\text{A}$	0.2		0.2		V
		$I_{OL} = 24\text{ mA}$	0.5		0.5		
	$V_{CC} = 3\text{ V}$	$I_{OL} = 16\text{ mA}$	0.4		0.4		
		$I_{OL} = 32\text{ mA}$	0.5		0.5		
		$I_{OL} = 48\text{ mA}$	0.55				
		$I_{OL} = 64\text{ mA}$			0.55		
$I_I$	$V_{CC} = 3.6\text{ V}$ , $V_I = V_{CC}$ or GND		Control inputs		$\pm 1$		$\mu\text{A}$
	$V_{CC} = 0$ or $\text{MAX}^\ddagger$ , $V_I = 5.5\text{ V}$				10		
	$V_{CC} = 3.6\text{ V}$	$V_I = 5.5\text{ V}$	A or B ports§		100		
		$V_I = V_{CC}$			5		
		$V_I = 0$			-10		
$I_{off}$	$V_{CC} = 0$ , $V_I$ or $V_O = 0$ to $4.5\text{ V}$				$\pm 100$		$\mu\text{A}$
$I_{OZPU}^\parallel$	$V_{CC} = 0$ to $1.5\text{ V}$ , $V_O = 0.5\text{ V}$ to $3\text{ V}$ , $\overline{OE} = X$				$\pm 50$		$\mu\text{A}$
$I_{OZPD}^\parallel$	$V_{CC} = 1.5\text{ V}$ to $0$ , $V_O = 0.5\text{ V}$ to $3\text{ V}$ , $\overline{OE} = X$				$\pm 50$		$\mu\text{A}$
$I_I(\text{hold})$	$V_{CC} = 3\text{ V}$	$V_I = 0.8\text{ V}$	A or B ports		75		$\mu\text{A}$
		$V_I = 2\text{ V}$			-75		
$I_{OZH}$	$V_{CC} = 3.6\text{ V}$ , $V_O = 3\text{ V}$		1		1		$\mu\text{A}$
$I_{OZL}$	$V_{CC} = 3.6\text{ V}$ , $V_O = 0.5\text{ V}$		-1		-1		$\mu\text{A}$
$I_{CC}$	$V_{CC} = 3.6\text{ V}$ , $I_O = 0$ , $V_I = V_{CC}$ or GND		Outputs high		0.13 0.225		mA
			Outputs low		8.8 15		
			Outputs disabled		0.13 0.225		
$\Delta I_{CC}^\#$	$V_{CC} = 3\text{ V}$ to $3.6\text{ V}$ , One input at $V_{CC} - 0.6\text{ V}$ , Other inputs at $V_{CC}$ or GND		0.3		0.2		mA
$C_i$	$V_I = 3\text{ V}$ or $0$		4		4		pF
$C_{io}$	$V_O = 3\text{ V}$ or $0$		10		10		pF

† All typical values are at  $V_{CC} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

§ Unused terminals at  $V_{CC}$  or GND

¶ This parameter is specified by characterization but is not production tested.

# This is the increase in supply current for each input that is at the specified TTL voltage level rather than  $V_{CC}$  or GND.



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switching characteristics over recommended operating free-air temperature range,  $C_L = 50$  pF (unless otherwise noted) (see Figure 1)

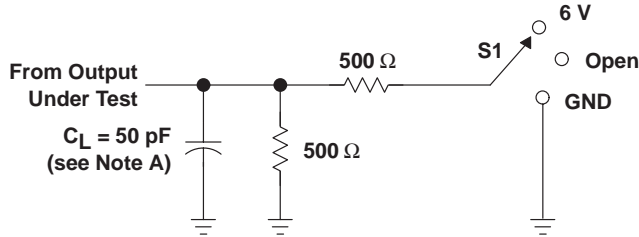
PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTZ245				SN74LVTZ245				UNIT	
			$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CC} = 2.7\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$			$V_{CC} = 2.7\text{ V}$		
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN		MAX
$t_{PLH}$	A or B	B or A	1	4.6	5.3		1	2.5	4	5.2		ns
$t_{PHL}$			1	4.1	5.7		1	2.5	4	5.5		
$t_{PZH}$	$\overline{OE}$	A or B	1.1	6.1	7.2		1.1	3.3	5.9	7.1		ns
$t_{PZL}$			1.5	6.6	8		1.5	3.8	6.5	7.9		
$t_{PHZ}$	$\overline{OE}$	A or B	2.2	6.2	7		2.2	4.3	5.9	6.5		ns
$t_{PLZ}$			2	5.7	5.9		2	3.9	5.5	5.6		

† All typical values are at  $V_{CC} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

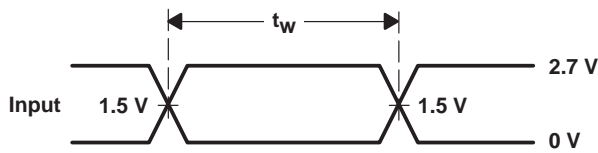
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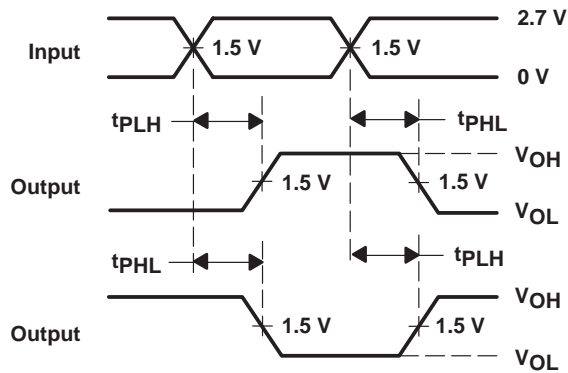
## PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT FOR OUTPUTS

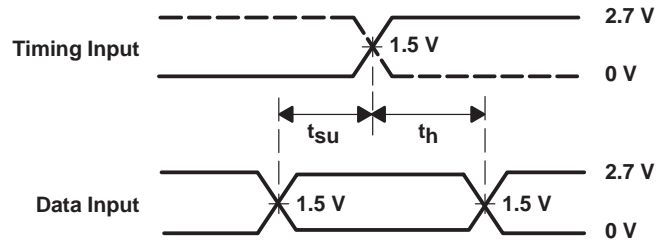


VOLTAGE WAVEFORMS  
PULSE DURATION

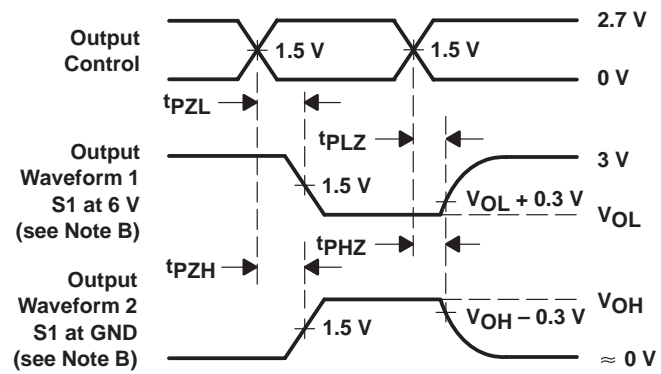


VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTS

TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	6 V
$t_{PHZ}/t_{PZH}$	GND



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A.  $C_L$  includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.  
 C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10$  MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2.5$  ns,  $t_f \leq 2.5$  ns.  
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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